

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IPW60R180C7

IIPW60R180C7

• FEATURES

- Static drain-source on-resistance: $R_{DS}(on) \leqslant 180 m_{\Omega}$
- · Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

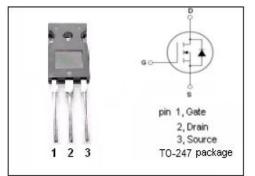
Fast Switching

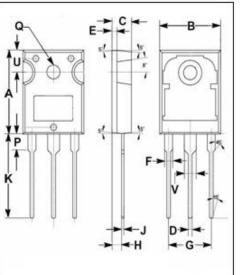
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

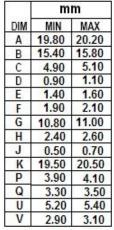
SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	600	V
V_{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous	13	А
I _{DM}	Drain Current-Single Pulsed	45	A
PD	Total Dissipation @Tc=25°C	68	W
Tj	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.832	°C/W
Rth(j-a)	Channel-to-ambient thermal resistance	62	°C/W









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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =1mA	600			v
$V_{GS(th)}$	Gate Threshold Voltage	VDS=VGS; I _D =0.26mA	3		4	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V _{GS} =10V; I _D =5.3A			180	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = 20V; VDS=0V			0.1	μ Α
I _{DSS}	Drain-Source Leakage Current	V _{DS} =600V; V _{GS} = 0V			1	μ Α
V _{SD}	Diode forward voltage	I _F =5.3A, V _{GS} = 0V				v

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